

COUPLING MECHANISM FOR A PCB MOUNTED MICROWAVE
RE-ENTRANT RESONANT CAVITY

The present invention relates to an apparatus comprising a resonant
5 cavity mounted on a Printed Circuit Board PCB and a coupling mechanism to
couple microwave signals from a transmission line embedded in said PCB to
said resonant cavity, said resonant cavity being provided with a re-entrant inner
stub orthogonal to said PCB and separated from said PCB by a capacitive gap.

The RF front-end filtering/duplexing device constitutes one of the
10 most critical devices for the performance and compliance of modern cellular,
high-power, base-stations (BTS). Due to the requirement for high overall BTS
power efficiency and the strict compliance rules imposed by the regulatory
authorities, the transfer function of these filtering/duplexing devices should meet
several stringent specifications such as minimal in-band insertion loss, maximal
15 out-of-band rejection, and high close-to-band selectivity. The implementation of
such transfer functions, together with the high-power handling capability that is
usually required, result into filtering devices that are bulky in volume and
expensive in their fabrication.

In terms of the underlying RF technology, these filters are usually
20 composed of waveguide/cavity resonators, coupled through irises or other
defects on the walls that form the cavities. Given that the exact dimensions of
the resonating cavities and the employed coupling mechanisms determine the
filters' RF characteristics (operation band, insertion loss, return loss) high
mechanical accuracy is required during their fabrication. Nevertheless, the
25 required accuracy is almost never achieved during the production process and,
therefore, post-production manual tuning is required for the optimization of the
filters' transfer function.

Future cellular networks, able to support much higher data rates and
heavier traffic, are envisioned to be composed of smaller cells (smaller radiated
30 power per BTS) or to employ BTS composed of several modular radios,
radiating medium power levels per element (e.g. Active Antenna Arrays). In

such cases, the reduced power radiated by each BTS RF front-end could allow for relaxed filter requirements (e.g. relaxed requirements for the in-band insertion losses or the close-to-band selectivity), but the architecture of these BTS would impose some extra requirements related with the filters' volume and weight, and their integrability with the remaining RF front-end.

Given these new requirements, the filtering/duplexing devices of future, small cell or modular BTS could resemble more those currently employed in mobile terminals than the traditional high-power filtering/duplexing devices of modern BTS. In reality, filtering technologies that position themselves between these two extreme cases (in terms of their quality performance and their size properties) would be the most suitable for such applications.

Ceramic filters are one of the technologies that could provide niche solutions for such applications. Nevertheless, the design of such filters meeting medium power-handling specifications (e.g. average power greater than 4 W) or strict isolation conditions (e.g. Tx/Rx isolation for the FDD LTE 2.6 GHz band) is not always possible. Besides, the cost of this technology is very much dependant on the production volume, and unless such filters are produced in multi-million quantities, the cost per filter remains relatively high.

Another filtering technology that could be employed in applications that require simultaneously high quality filtering performance and relatively small-size properties or integrability features is the surface-mount filtering technology. In this approach, 3-D resonant cavities (able to deliver high-Q values), such as re-entrant (coaxial) resonators, are mounted on conventional Printed Circuit Boards PCBs. These cavities are interconnected through transmission lines embedded in the PCB. The same transmission lines are also used for the implementation of the required filtering function. In that way, the filtering devices can be integrated with the remaining of the RF front-end on the same PCB.

A cross-sectional representation of a conventional microwave re-entrant (coaxial) resonator mounted on a Printed Circuit Board PCB is depicted in Fig. 1. In this configuration, the 3-D part of a resonator

soldered (through a soldering layer **13**) on the external metalized surface of the Printed Circuit Board PCB **14**. In this case, both the 3-D part of the resonator **10** and the external surface of the PCB that is bounded by the 3-D component are forming a resonant cavity **15**. As far as the 3-D part of the resonator **10** is concerned, it is composed of an outer wall **11**, an internal re-entrant stub/rod **12** and may be of either cylindrical or rectangular shape (in a coaxial configuration). This part can be formed by either milling in or casting from a metallic volume, or by metal-plating plastic 3-D forms (for weight reduction).

The electromagnetic properties of the resonant, air-filled cavity **15** are dependent on the exact dimensions of the effective coaxial configuration (i.e. the length of the inner rod **12** and its distance from the external wall **11** of the cavity) and the capacitive gap **16** formed between the inner rod **12** and the external metalized surface of the PCB that comprises part of the resonant cavity.

For the synthesis of microwave filtering structures using resonant cavities similar with that of Fig. 1, microwave signals have to be guided to and away from the cavity. This can be done through the employed PCB and by embedding on it different types of transmission lines. This is also schematically represented in Fig. 1, where an embedded on the PCB input waveguide/transmission line **17** guides the microwave signal to the cavity, feeds the signal into the cavity through a coupling mechanism **18** and then the resonating signal is fed through another coupling mechanism **19** to an output waveguide/transmission line **20**.

Then, microwave filters can be synthesized based on conventional filter synthesis models such as that of Fig. 2, where the employed resonators **30** are interconnected through admittance inverters **31**, properly synthesized to implement specific transfer functions. In the case of cavities such as that of Fig. 1, the inverters can be designed using also PCB-embedded transmission lines.

For the implementation of resonant cavities such as that of Fig. 1, the design of the coupling mechanisms **18**, **19** in a way that the comparative

advantages of this configuration remain untouched (fully printed interconnecting lines and coupling mechanisms) constitutes the most challenging part.

Solutions are proposed, e.g., in documents of Jan Hesselbarth such as the Patent Application **WO 2008/036180 A2** entitled "Re-entrant resonant cavities, filters including such cavities and method of manufacture", the Patent Application **WO 2008/036179 A1** entitled "Resonant cavities and method of manufacturing such cavities", the Patent Application **WO 2008/036178 A1** entitled "Re-entrant resonant cavities, filters including such cavities and method of manufacture", and the publication "Surface-mount cavity filter technology", in Proc. European Microwave Conference 2007, pp. 442-445, Oct. 2007.

Therein, the above challenge was tackled by splitting the 3-D resonant cavity in two halves and locating the first half of the cavity on the upper external surface of the PCB and other half of the cavity on the lower external surface of the PCB, as shown in Fig. 3. In this configuration, the two parts of the cavity were electrically connected through the PCB, using the via posts **44** embedded in the PCB, and the microwave signals were coupled electrically to and from the inner stub of the cavity through transmission lines **45** that were penetrating the cavity. This approach was experimentally validated, but, given that the PCB itself and the interconnecting via posts were part of the resonant cavities, the operation of the cavities in this configuration were usually accompanied with relatively high losses (decreased quality factors).

The major challenge in the design of coupling mechanisms for the feeding of microwave signals to and from PCB mounted 3-D resonant cavities is to retain the major comparative advantages of such configurations (high $-Q$ resonators interconnected through fully-printed PCB-embedded networks), while achieving the desired functionality of low loss coupling mechanism providing a large range of coupling coefficients and some tunability for the cavity resonances.

An object of the present invention is to provide a coupling mechanism to feed microwave signals to a 3-D PCB mounted resonant cavity,

similar with that of Fig. 1 described above, but which implements an easy-to-fabricate mechanism leading to high-quality filtering.

According to a characterizing embodiment of the invention, this object is achieved due to the fact that the end of said transmission line is provided with a metalized feeding pad located at the external layer of said PCB inside said resonant cavity, and that said metalized feeding pad is facing said inner stub in the area of said capacitive gap and is offset from the axial direction of said inner stub.

In this way, the size and position of the metalized feeding pad defines and allows adjusting the coupling mechanism while providing high-quality filtering with reproducible characteristics.

The proposed filter technology exhibits considerably improved performance as compared to the filter technology of the known prior art. The present technology is more robust to manufacturing errors and the operation of the resulting RF filters is associated with significantly reduced insertion losses (easier to maintain the high-Q values of the 3-D resonant cavities).

It is to be noted that the Patent Application US 2005/200424 A1 (15 September 2005) of Hideji Takeda [JP] et al and entitled "Microstripline waveguide converter" discloses that in the inside of the converting portion of a microstripline waveguide converter, on the backside surface of a dielectric substrate, which constitutes, for example, a "stripline antenna", a strip conductor pattern, which serves as a half-wavelength strip resonator, is disposed, to thereby add a band rejection function to the converter. The size of the converter is thereby reduced.

However, this known device do not comprise a resonant cavity provided with a re-entrant inner stub orthogonal to the PCB. This known document do further not disclose nor teach the advantageous characteristic features of the present invention.

Other Patent Applications may also constitute background information for the present invention. For instance:

- US 2008/024249 A1 (31 January 2008) of Gerhard Schreibvogel [AT] and entitled "High-Frequency Filter" relates to a high-frequency filter that has the following features: a substrate is provided that is made of dielectric material and comprises a first face and an opposite second face. At least one stripline is applied to the first face of the substrate, at least one resonator is provided which is electrically coupled to the at least one stripline and a ground area is provided that is spaced apart from the stripline. The resonator is embodied as a coaxial resonator comprising an outer conductor pot and a substantially rod-shaped inner conductor which is disposed coaxially in the outer conductor pot. The outer conductor pot is galvanically connected to the ground area. A first end of the inner conductor is galvanically connected to the bottom of the outer conductor pot. The resonator is electrically coupled to the at least one stripline via an opposite second end of the inner conductor;

- EP 1 304 762 A2 (23 April 2003) of Dwan Debasis [JP] et al (FUJITSU COMPOUND SEMICONDUCTOR [US], FUJITSU QUANTUM DEVICES LTD [JP]) and entitled "Transmission line to waveguide transition structures" discloses that a planar structure is provided for coupling electromagnetic signals between a planar transmission line and a waveguide. The planar structure comprises a shielded patch antenna and one or more capacitive diaphragms disposed adjacent to the patch antenna. This structure is advantageous to MMIC (Monolithic Microwave Integrated Circuit) modules in connecting from a planar transmission line of a substrate carrying a MMIC to an external waveguide without the need of a non-planar back metal short, which is normally essential to avoid back scattering from waveguide and also normally needed to achieve impedance matching. The disclosed patch antenna radiates into the waveguide, while the antenna's ground plane reduces back scattering from the waveguide. The one or more capacitive diaphragms provide impedance matching between the microstrip and the waveguide;

- US 2008/068111 A1 (20 March 2008) of Jan Hesselbarth [IE] and entitled "Re-entrant resonant cavities, filters including such cavities and method of manufacture" discloses a re-entrant microwave resonant cavity that

comprises a stub. A cylindrical wall, first end wall and the stub are integrally formed. A second end wall is defined by a metallization layer deposited on a printed circuit board substrate. The parts are joined using surface mount soldering processes. The end of the stub defines a gap. A rostrum faces the
5 end of the stub. The rostrum is manufactured separately and then fixed to the substrate. A dielectric sphere is located between the end of the probe and the rostrum. The dielectric sphere maintains the gap size during use and aids in correct positioning of the parts during manufacture; and

- US 2008/297283 A1 (4 December 2008) of Woo-jin Byun (KR) et al
10 and entitled "Mode Transition Circuit for Transferring Radio Frequency Signal and Transceiver Module Having the Same" discloses a mode transition circuit for transferring a RF signal and a transceiver module having the same. The mode transition circuit includes: a planar transmission line mounted at a RF substrate for receiving a RF signal from a RF signal generating unit; a via
15 formed inside the RF substrate and connected to one side of the planar transmission line for receiving the RF signal from the planar transmission line; at least one of metal patches formed inside the RF substrate and connected to the one side of the via for receiving the RF signal from the via; and a hole formed inside a low frequency substrate and connected to one side of the metal
20 patch for receiving the RF signal from the metal patch.

However, again none of these known documents disclose nor teaches the subject of the present invention. Also another characterizing embodiment of the present invention is that said resonant cavity is mounted on an external metalized surface of said PCB, and that said metalized feeding pad
25 is separated from said external metalized surface by a surface capacitive gap.

The capacitive gap formed by relative position of the metalized feeding pad in offset with respect to the axial direction of the re-entrant inner stub and the surface capacitive gap separating the metalized feeding pad from the external metalized surface of the PCB define the characteristics of the
30 coupling mechanism.

In a preferred characterizing embodiment of the present invention, said metalized feeding pad has the shape of a disk surrounded by said surface capacitive gap and whereof the centre is offset from the axial direction of said inner stub.

5 Although the metalized feeding pad may have most any shape, it has been proved that a disk form leads to optimal results.

 In a variant embodiment of the present invention, said PCB is provided with an input embedded transmission line of which an input end is provided with an input metalized feeding pad, and with an output embedded
10 transmission line of which an output end is provided with an output metalized feeding pad, and said input and output metalized feeding pads are located at the external layer of said PCB inside said resonant cavity and are separated by an electric wall.

 The proposed filter technology provides a niche solution for
15 applications (RF front-ends of modern BTS/ nodeB/ e-nodeB/ etc) that require high-quality filtering performance and relatively high-power handling capabilities together with low-volume properties and a high degree of integration (filter integrated with the other components of the RF front-end). These features together with its low-cost and fully-automated fabrication process (fully-printed
20 PCB/ soldered top-mounted metalized-plastic cavities) make the present coupling mechanism a very promising technology for future PCB mounted microwave re-entrant resonant cavities.

 Further characterizing embodiments of the present coupling mechanism are mentioned in the appended claims.

25 It is to be noticed that the terms "comprising" or "including", used in the claims, should not be interpreted as being restricted to the means listed thereafter. Thus, the scope of an expression such as "a device comprising means A and B" should not be limited to an embodiment of a device consisting only of the means A and B. It means that, with respect to embodiments of the present invention, A and
30 B are essential means of the device.

Similarly, it is to be noticed that the term "coupled", also used in the claims, should not be interpreted as being restricted to direct connections only. Thus, the scope of the expression such as "a device A coupled to a device B" should not be limited to embodiments of a device wherein an output of device A is
5 directly connected to an input of device B. It means that there may exist a path between an output of A and an input of B, which path may include other devices or means.

The above and other objects and features of the invention will become more apparent and the invention itself will be best understood by
10 referring to the following description of an embodiment taken in conjunction with the accompanying drawings wherein:

Fig. 1 shows a classical resonant cavity formed by a 3-D re-entrant (coaxial) resonator mounted on a PCB;

Fig. 2 represents a filter synthesis model of the resonant cavity of
15 Fig. 1 employing admittance inverters;

Fig. 3 shows another PCB-mounted resonant cavity as known from prior art;

Fig. 4 shows a coupling mechanism employed to couple signals from a PCB-embedded waveguide (stripline) to a single PCB-mounted resonant
20 cavity according to an embodiment of the invention;

Fig. 5 is a top-view of the coupling mechanism of Fig. 4 at the level of the external surface of the PCB, with respect to the location of the mounted 3-D resonant cavity;

Fig. 6 represents an equivalent circuit of the coupling mechanism of
25 Figs. 4 and 5;

Fig. 7 shows a coupling mechanism employed to couple signals from a PCB-embedded waveguide (stripline) to a single resonant cavity and reverse according to another embodiment of the invention;

Fig. 8 shows a coupling mechanism employed to couple signals from
30 a PCB-embedded waveguide (stripline) to a pair of inductively coupled resonant cavities and reverse according to another embodiment of the invention;

Fig. 9 represents a filter synthesis model according to the configuration of Fig. 8;

Fig. 10 shows a 3-D model of a 4-pole Chebyshev filter that employs a coupling mechanism according to an embodiment of the present invention to couple the microwave signal from a PCB-embedded waveguide (stripline) to the 3-D resonant cavities and reverse;

Fig. 11 is a bottom-view of a single pair of inductively coupled resonant cavities employed in the 3-D model of Fig. 10;

Fig. 12 is a cross-section view of the 3-D model of Fig. 10 along a single pair of inductively coupled resonant cavities;

Fig. 13 shows a coupling mechanism of the microwave signal from the PCB-embedded striplines (131) to the inductively coupled pair of resonant cavities; and

Fig. 14 represents a simulated response of the 4-pole filter of Fig. 10. An embodiment of a coupling mechanism, that fulfills all the requirements of the present invention, is presented in Fig. 4 and Fig. 5.

A cross-sectional representation of a Printed Circuit Board PCB mounted microwave re-entrant resonant cavity is shown at Fig. 4, while Fig. 5 shows a top-view of the coupling mechanism at the level of the external surface of the PCB, with respect to the location of the mounted 3-D resonant cavity.

As in a conventional microwave re-entrant (coaxial) resonator mounted on a PCB, the 3-D part of the present resonator is soldered on an external metalized surface of the PCB. Both the 3-D part of the resonator and the external surface of the PCB that is bounded by the 3-D component are forming a resonant cavity **60**. The 3-D part of the resonator is composed of an outer wall, an internal re-entrant stub or rod **64** and may be of either cylindrical or rectangular shape (in a coaxial configuration). This part can be formed by either milling in or casting from a metallic volume, or by metal-plating plastic 3-D forms, mainly for weight reduction.

The re-entrant inner rod **64** is orthogonal to the PCB with one end fixed to the outer wall and the other end facing the PCB and separated thereof by a capacitive gap **66**.

5 The electromagnetic properties of the resonant, air-filled resonant cavity **60** are dependent on the exact dimensions of the effective coaxial configuration (i.e. the length of the inner rod **64** and its distance from the external wall of the cavity) and the capacitive gap **66** formed between the inner rod **64** and the external metalized surface of the PCB that comprises part of the resonant cavity.

10 The microwave signal is considered to be guided to the resonator through an embedded waveguide/transmission line **61** that employs the external metalized surface of the PCB, on which the 3-D cavity is mounted, as a ground plane. This line can be implemented, for example, in either microstrip or stripline technology. When the microwave signal reaches the end of the feeding
15 transmission line, it is guided through a vertical via post (or an array of via posts) **62** to a metalized feeding pad **63** located, inside the cavity, at the external layer of the PCB on which the 3-D resonator is mounted.

In Fig 5, the top view of this metalized feeding pad **71**, with respect to the location of the coaxial configuration **72** of the resonant cavity mounted on
20 the external surface of the PCB **73**, is clearly depicted. Given that between the feeding pad **71** and the external surface **73** of the PCB there is no electrical connection, a displacement current will be supported across a surface capacitive gap **74** formed between them.

The metalized feeding pad **63/71** preferably has the shape of a disk
25 which is surrounded by the surface capacitive gap **74** and whereof the centre is offset from the axial direction of the internal re-entrant stub/rod **64**.

This is the first mechanism of electromagnetic coupling of the feeding microwave signal to the resonant cavity, given that the part of the external surface of the PCB around the metalized feeding pad comprises part of the
30 resonant cavity, as was shown in Fig. 4.

The electromagnetic properties of this coupling (i.e. magnitude) are depended on the radius of the pad and the width of the surface capacitive gap **74**. Both these features can be adjusted when designing the PCB, irrespectively of the 3-D part of the resonant cavity, and constitute significant design parameters while synthesizing a specific filtering transfer function and the corresponding PCB layout.

The second mechanism of electromagnetic coupling between the metalized feeding pad **63/71** and the resonant cavity is the capacitance supported between the inner stub **64** of the 3-D coaxial configuration and the feeding pad itself.

As shown in Fig. 5, the feeding pad and the inner stub of the resonator overlap over a surface **75** that is dependent on the radius of the feeding pad and its position (offset) with respect to the centre of the coaxial configuration of the 3-D part of the resonator. These two parameters constitute another two major design parameters that should be properly set during the filter synthesis and PCB layout design. The importance of this second coupling mechanism is attributed to the fact that apart from providing electromagnetic coupling between the feeding pad and the resonant cavity, it provides a means of slightly adjusting and tuning the resonance of the resonant cavity through the design/layout of the PCB.

Specifically, with the introduction of the feeding pad, the total capacitance supported between the external layer of the PCB on which the 3-D cavity is mounted and the inner stub of the coaxial configuration, that originally played a key role in the estimation of the total capacitance of the resonating cavity and its resonant frequency, is divided into two components. The first is the capacitance supported between the feeding pad and the inner stub of the 3-D part of the cavity and the second is the surface capacitance supported by the external PCB surface around the feeding pad overlaying with the inner stub of the 3-D part of the cavity. The ratio between these two capacitances should be equal with the ratio of the feeding pad surface and the external PCB surface overlaying with inner rod of the coaxial configuration and, hence, can be

adjusted by adjusting the position of the feeding pad. Although the sum of these two capacitances should be approximately equal with the total capacitance of the first case, in the latter case the capacitance between the feeding pad and the inner stub of the coaxial configuration does not influence the capacitive characteristics and the resonant frequency of the resonant cavity.

Therefore, by altering (increasing/decreasing) this capacitance, the total capacitance of the resonant cavity can be inversely altered (decreased/increased). By this means, the effective resonant frequency of the resonant cavity can be adjusted through the design of the layout of the external PCB surface.

In order to schematically represent the major properties of the proposed coupling mechanism, the equivalent circuit of a configuration similar with that of Fig. 4 is shown in Fig. 6. In this equivalent circuit, the resonant cavity is represented through a shunt LC circuit that is composed of an inductance L_{coax} and a capacitance C_{coax} that are attributed to the 3-D coaxial configuration, and a capacitance C_{gap} that is attributed to the capacitance supported between the inner stub of the coaxial configuration and the PCB surface on which the 3-D cavity is mounted and comprises part of the resonant cavity.

In the absence of the feeding pad, this capacitance is depended exclusively on the geometrical characteristics of the gap (gap width d and total area S over which the capacitance is supported $C_{\text{gap}} = \epsilon_0 S/d$) and directly loads the coaxial resonator ($C_0 = C_{\text{gap}}$ according to the notation of Fig. 6).

In the presence of the feeding pad, this capacitance is split in two components: one of them, that is supported between the inner stub of the resonator and the ground plane, loads the coaxial resonator similarly as before, and the second, that is supported between the inner stub of the resonator and the feeding pad, corresponds to a coupling capacitance that is serially connected to the resonator. The ratio between these two capacitances is defined by the fraction of the inner stub area overlapping with the feeding disk. Therefore, if the overlapping ratio is considered to be k , then $C_0 = (1-k) C_{\text{gap}}$

and $C_{ser} = k C_{gap}$. Finally, the coupling capacitance between the feeding disk and the external surface of the PCB that comprises part of the resonant cavity can be considered to be in parallel with the resonator (C_{sh} in Fig. 6).

In a conventional filter configuration, electromagnetic signals have to
5 be guided to and from each of the resonators that comprises the filter, as shown in Fig. 1. Therefore, two coupling mechanisms, similar with those presented in the previous text, are required to be implemented within each of the cavities. This is depicted in Fig. 7, where an input transmission line **81** guides the signal to an input metalized feeding pad in the cavity through the coupling mechanism
10 **82**, while the coupling mechanism **83** couples the signal from an output metalized feeding pad in the cavity to an output transmission line **84**.

The configuration of Fig. 7 is prone to several parasitic phenomena that may influence, deteriorate or limit the operation of the cavity resonator as part of a microwave filter. Given its compact size, the coupling mechanisms **82**
15 and **83** are located close to each other.

This may result in some direct coupling between them, either through the resonant cavity itself or through the substrate on which the cavity is mounted, deteriorating the electromagnetic performance of the resonator.

Even though the latter case can be addressed with the use of an
20 electric wall **85** inserted between them (this wall can be implemented using closely spaced coppers vias), there is very little to be done to avoid direct electromagnetic coupling between the two coupling mechanism through the resonant cavity. In fact, a simple solution to this problem would be to keep them as far as possible from each other.

25 Nevertheless, this approach would reduce the overlapping area between each of the coupling disks and the inner stub of the resonator (**75** in Fig. 5) and therefore the total achievable coupling coefficient implemented by each of those mechanisms. Therefore, a configuration similar with that of Fig. 7 may not be the preferred implementation of filters composed of cavity
30 resonators mounted on a PCB.

A preferred alternative implementation of such filters is shown in Fig. 8. In the context of this implementation, the modular elements for the design of PCB-mounted resonant cavity filters are considered to be pairs of inductively coupled 3-D resonant coaxial cavities, similar with that shown in Fig. 8. In this approach, any two of the 3-D coaxial resonators have to be built within one block **91**. On the common electric wall **95** separating the input resonant cavity from the output resonant cavity, an iris open window **92** secures the inductive coupling between the two cavities built on the same block. The input/output resonant cavity of the pair is provided with a distinct input/output inner stub orthogonal to the PCB and separated thereof by an input/output capacitive gap, respectively. Moreover, an input metalized feeding pad is implemented in the input resonant cavity of the pair, whilst an output metalized feeding pad is implemented in the output resonant cavity of the pair. The input metalized feeding pad is facing the end face of the input inner stub in the area of the input capacitive gap and is offset from the axial direction of this input inner stub, whilst the output metalized feeding pad is facing the end face of the output inner stub in the area of the output capacitive gap and is offset from the axial direction of this output inner stub.

The exact dimensions of the coupling window **92** determine the magnitude of the corresponding inductive coupling.

The advantage of a configuration similar with that of Fig. 8 is that it allows to feed the microwave signal from the PCB to the input cavity through the input coupling mechanism **93** and then couple out the filtered signal from the output cavity to the PCB through the output coupling mechanism **94**.

In that way, the two PCB-cavity coupling mechanisms are implemented in two different cavities and therefore no significant parasitic direct coupling between them (through the cavities) is present.

Furthermore, the design parameters associated with each of the two coupling mechanisms (i.e. feeding disk diameter, position of the feeding disk etc) are free to be chosen according to the requirements of the filter design

procedure without having to satisfy any major restrictions (i.e. size, relative position of the two coupling mechanisms etc).

When the configuration of Fig. 8 is employed for the synthesis of filtering devices, the filter functions should be synthesized according to the model of Fig. 9. In this model, the input and output coupling to and from the first and last resonator of the filter is implemented through transmission line based admittance inverters (J_{01} and J_{NN+1}), while the coupling between the resonators are implemented interchangeably using inductive coupling irises (M_{ij}) and transmission line based impedance inverters (J_{ij}).

In order to verify the possibility of designing PCB-mounted filters employing 3-D re-entrant (coaxial) resonators excited and interconnected by means of the coupling mechanisms proposed in this invention, a 4th-order Chebyshev filter has been designed and simulated. The targeted operating band for this filter has been the downlink Tx band of the WCDMA air interface (2110 MHz – 2170MHz).

The model employed for the simulation of this filter is depicted in Fig. 10. For this filter implementation, the configuration of Fig. 8 was employed. Specifically, the four resonators of the 4th order filter were built in two pairs of inductively coupled resonators. Then these two pairs were interconnected through admittance inverters implemented on the PCB and the filter function was synthesized according to the model of Fig 9.

Referring to the 3-D model of Fig. 10, the two pairs of inductively coupled cavities are milled in two metallic volumes **100**. These volumes are considered to be soldered on the top surface of a PCB **101** that is metal-plated on both its upper and lower sides. Inside the PCB, striplines are employed to synthesize the interconnecting admittance inverters. Furthermore, copper vias **102** have been embedded within the PCB, shorting the two sides of the PCB (ground planes of the employed striplines), to enhance electromagnetic isolation between the coupling mechanisms and reduce the parasitic effects associated with the operation of the striplines.

The bottom view of each of the two inductively coupled pairs of the re-entrant resonators milled in metallic volumes (**100** in Fig. 10) is depicted in Fig. 11. In this implementation, the two resonant cavities **110** are composed of cylindrical inner rods **111** and rectangular outer walls **112**. In the general case, the shapes of the inner and outer contactors can be any that support a similar coaxial configuration. Finally, the two cavities are coupled through an iris **113** that is formed by removing material from the walls separating the two cavities.

In Fig. 12, the cross-section of the 3-D filter model along one pair of inductively coupled cavities is depicted. As shown, the signal is guided to and from the pair of cavities through the striplines **123** that have been embedded in the PCB that bares the cavities. The aforementioned striplines use metallic surfaces 121 and 122 as upper and lower ground planes, while the surface 121 is also used to attach on the 3-D parts of the resonant cavities. These striplines are connected with the feed disks of the upper ground plane layer 121 of the PCB using copper vias **124**.

A better representation of the mechanisms that couple the signals from the striplines to the resonant cavities through the vias and the feeding disks is shown in Fig. 13. Specifically, in Fig. 13, input/output striplines 131 feed the RF signal to coupling disks 132 that have been formed on a metallic surface 130 that, apart from operating as an upper ground plane for the stripline, also is used to attach the 3-D resonant cavity.

Finally, the full-wave simulated response of the 4-pole Chebyshev filter of Fig. 10 is depicted in Fig. 14, which represents the S-parameters in dB (vertical axis) of the aforementioned filter structure against the frequency bands in GHz of interest (horizontal axis). According to these results, low insertion loss is achieved across the passband of the filter (<0.6 dB) while a better than 50 dB isolation for the downlink Rx band of the WCDMA air interface is also achieved.

It is to be noted that the present coupling mechanism can be used to couple signals not only to/from single or double cavities but in a more general case to structures composed of an arbitrary large number of cavities. To this end, the general coupling mechanism comprises several resonant cavities

mounted on the PCB, which is provided with a same amount of embedded transmission lines each having an end provided with a metalized feeding pad located inside a distinct one of the resonant cavities. Each resonant cavity is provided with an inner stub orthogonal to the PCB and separated thereof by a capacitive gap. Each metalized feeding pad is facing the end face of a corresponding inner stub in the area of the capacitive gap and is offset from the axial direction of the corresponding inner stub. The metalized feeding pads are further separated by electric walls.

A final remark is that embodiments of the present invention are described above in terms of functional blocks. From the functional description of these blocks, given above, it will be apparent for a person skilled in the art of designing electronic devices how embodiments of these blocks can be manufactured with well-known electronic components. A detailed architecture of the contents of the functional blocks hence is not given.

While the principles of the invention have been described above in connection with specific apparatus, it is to be clearly understood that this description is merely made by way of example and not as a limitation on the scope of the invention, as defined in the appended claims.

CLAIMS

1. An apparatus comprising a resonant cavity (60) mounted on a Printed Circuit Board PCB (67) and a coupling mechanism to couple microwave signals from a transmission line (61) embedded in said PCB to said resonant cavity,

said resonant cavity being provided with a re-entrant inner stub (64) orthogonal to said PCB and separated from said PCB by a capacitive gap (66),

characterized in that the end of said transmission line (61) is provided with a metalized feeding pad (63) located at the external layer of said PCB (67) inside said resonant cavity (60),

and in that said metalized feeding pad (63) is facing said inner stub in the area of said capacitive gap and is offset from the axial direction of said inner stub (64).

2. The apparatus according to claim 1,

characterized in that said resonant cavity (60) is mounted on an external metalized surface (73) of said PCB (67),

and in that said metalized feeding pad (63, 71) is separated from said external metalized surface by a surface capacitive gap (74).

3. The apparatus according to the claims 1 and 2, **characterized in that** said metalized feeding pad (63, 71) has the shape of a disk surrounded by said surface capacitive gap (74) and whereof the centre is offset from the axial direction of said inner stub (64).

4. The apparatus according to claim 1, **characterized in that** the end of said transmission line (61) is coupled to said metalized feeding pad (63) through at least one via post (62).

5. The apparatus according to claim 1, **characterized in that** said transmission line (61) embedded in said PCB (73) is a waveguide implemented in microstrip or stripline technology.

5 6. The apparatus according to claim 1,
 characterized in that said PCB is provided with an input embedded transmission line (81) of which an input end is provided with an input metalized feeding pad, and with an output embedded transmission line (84) of which an output end is provided with an output metalized feeding pad,

10 **and in that** said input and output metalized feeding pads are located at the external layer of said PCB inside said resonant cavity and are separated by an electric wall (85).

 7. The apparatus according to claim 6,
15 **characterized in that** said resonant cavity is provided with a re-entrant inner stub orthogonal to said PCB which is separated from said PCB by a capacitive gap,

and in that said input and output metalized feeding pads are both facing an end face of the inner stub in the area of said capacitive gap, and are
20 each offset from the axial direction of said inner stub.

8. The apparatus according to claim 6, **characterized in that** said electric wall (85) is implemented by closely spaced coppers vias in said PCB.

25 9. The coupling mechanism according to claim 6,
 characterized in that said resonant cavity mounted on said PCB is constituted by a pair of inductively coupled 3-D resonant cavities built within a same block (91),

in that an input resonant cavity of said pair is provided with an input
30 inner stub orthogonal to said PCB and separated from said PCB by an input capacitive gap, and an output resonant cavity of said pair is provided with an

output inner stub orthogonal to said PCB and separated from said PCB by an output capacitive gap,

in that said input and output resonant cavities are separated by a common electric wall (95),

5 **in that** an iris open window (92) is provided between said input and output resonant cavity of said pair,

and in that said input metalized feeding pad is implemented in said input resonant cavity of said pair, and said output metalized feeding pad is implemented in said output resonant cavity of said pair.

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10. The apparatus according to claim 9,

characterized in that said input metalized feeding pad is facing the end face of said input inner stub in the area of said input capacitive gap and is offset from the axial direction of said input inner stub, and said output metalized feeding pad is facing said end face of the output inner stub in the area of said output capacitive gap and is offset from the axial direction of said output inner stub.

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11. The apparatus according to claim 1,

20 **characterized in that** said coupling mechanism comprises a plurality of resonant cavities mounted on said PCB,

in that said PCB is provided with a plurality of embedded transmission lines each having an end provided with a metalized feeding pad located inside a distinct resonant cavity of said plurality of resonant cavities,

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in that each of said resonant cavities is provided with an inner stub orthogonal to said PCB and separated from said PCB by a capacitive gap,

in that each of said metalized feeding pad is facing an end face of a corresponding inner stub in the area of said capacitive gap and is offset from the axial direction of said corresponding inner stub,

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and in that said metalized feeding pads are separated by electric walls.